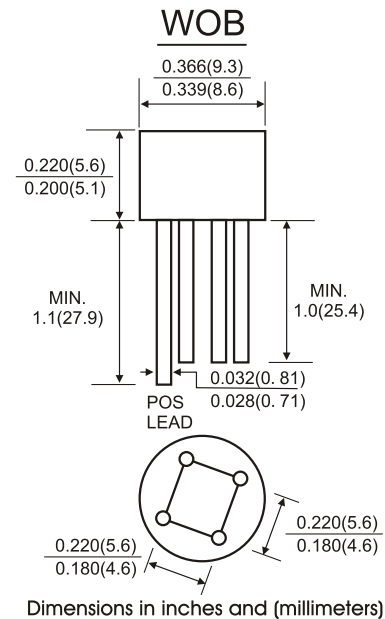


SILICON BRIDGE RECTIFIERS
VOLTAGE RANGE: 50 --- 1000 V
CURRENT: 1.5 A
FEATURES

- ◇ Rating to 1000V PRV
- ◇ Surge overload rating to 50 Amperes peak
- ◇ Ideal for printed circuit board
- ◇ Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- ◇ Mounting Position: Any
- ◇ Glass passivated chip junctions


MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		W005M	W01M	W02M	W04M	W06M	W08M	W10M	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward Output current @ $T_A=25^\circ\text{C}$	$I_{F(AV)}$	1.5							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I_{FSM}	50.0							A
Maximum instantaneous forward voltage at 1.0 A	V_F	1.0							V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	10.0 1.0							μA mA
Operating junction temperature range	T_J	- 55 --- + 125							°C
Storage temperature range	T_{STG}	- 55 --- + 150							°C

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FIG.1-TYPRCAL FORWARD CURRENT DERATING CURVE

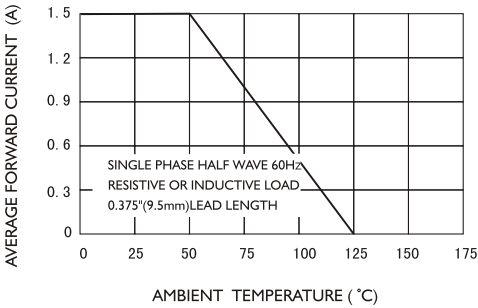


FIG.2-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

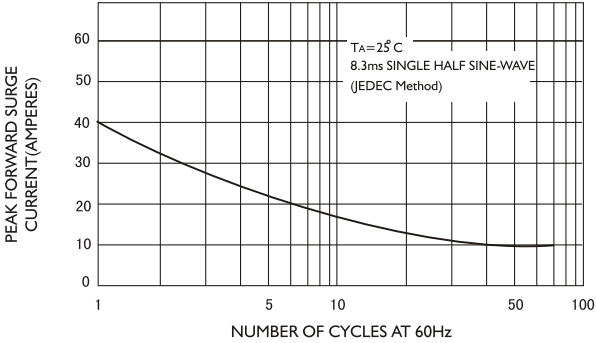


FIG3-TYPICAL FORWARD CHARACTERISTICS

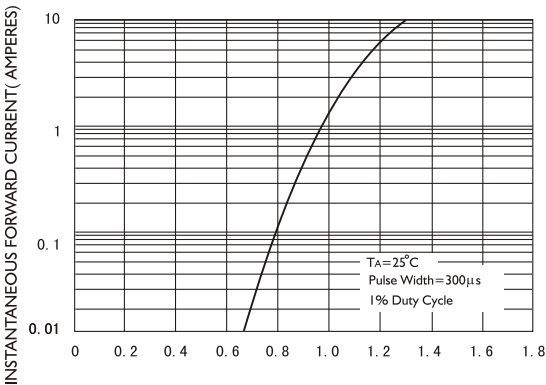


FIG.4-TYPICAL REVERSE CHARACTERISTICS

